

BoHS

COMPLIANT HALOGEN

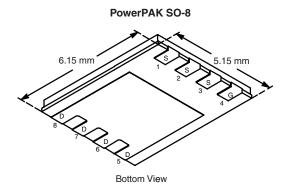
FREE

Available

Vishay Siliconix

N-Channel 30-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | | |
|---------------------|--|--------------------|-----------------------|--|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) | Q _g (Typ.) | | | |
| 30 | 0.004 at V_{GS} = 10 V | 28 | 36 | | | |
| | 0.0048 at V _{GS} = 4.5 V | 25 | 30 | | | |



Si7636DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

Ordering Information: Si7636DP-T1-E3 (Lead (Pb)-free)

Soldering Recommendations (Peak Temperature)^{b,c}

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- Ultra-Low On-Resistance Using High Density TrenchFET[®] Gen II Power MOSFET Technology

260

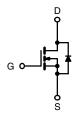
1.8

1.3

- Q_a Optimized
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile
- 100 % R_g Tested

APPLICATIONS

- Low-Side DC/DC Conversion
 - Notebook
 - Server
 - Workstation
- Synchronous Rectifier, POL



N-Channel MOSFET

Unit V

А

W

°C

Unit

°C/W

| ABSOLUTE MAXIMUM RATINGS T_A | _= 25 °C, unle | ss otherwise r | noted | | |
|--|------------------------|-----------------------------------|-------------|--------------|--|
| Parameter | | Symbol | 10 s | Steady State | |
| Drain-Source Voltage | | V _{DS} | 30 | | |
| Gate-Source Voltage | | V _{GS} | ± | 20 | |
| Continuous Drain Current (T _{.1} = 150 °C) ^a | T _A = 25 °C | I _D | 28 | 17 | |
| Continuous Drain Current $(T_{J} = 150 \text{ C})$ | T _A = 70 °C | | 22 | 13 | |
| Pulsed Drain Current (10 µs Pulse Width) | | I _{DM} | 60 | | |
| Continuous Source Current (Diode Conduction) ^a | | ۱ _S | 4.3 | 1.7 | |
| Avalanche Current | L = 0.1 mH | I _{AS} | 50 | | |
| Mauimum Davier Dissis ational | T _A = 25 °C | PD | 5.2 | 1.9 | |
| Maximum Power Dissipation ^a | T _A = 70 °C | U I | 3.3 | 1.2 | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | |

THERMAL RESISTANCE RATINGSParameterSymbolTypicalMaximumMaximum Junction-to-Ambienta $t \le 10 \text{ s}$ R_{thJA} 1924Steady State R_{thJA} 5265

Steady State

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

Maximum Junction-to-Case (Drain)

b. See Solder Profile (<u>http://www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

R_{thJC}

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit |
|---|---------------------|--|------|--------|--------|------|
| Static | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ | 1.0 | | 3.0 | V |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} – | $V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$ | | | 1 | μA |
| | | $V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$ | | | 5 | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$ | 30 | | | Α |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 25 \text{ A}$ | | 0.0033 | 0.004 | Ω |
| | | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 19 \text{ A}$ | | 0.004 | 0.0048 | |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = 15 \text{ V}, \text{ I}_{D} = 25 \text{ A}$ | | 110 | | S |
| Diode Forward Voltage ^a | V _{SD} | $I_{S} = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$ | | 0.72 | 1.1 | V |
| Dynamic ^b | | | • | | | |
| Input Capacitance | C _{iss} | V _{DS} = 15 V, V _{DS} = 0 V, f = 1 MHz | | 5600 | | pF |
| Output Capacitance | C _{oss} | | | 860 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 415 | | |
| Total Gate Charge Qg | | | | 36 | 50 | |
| Gate-Source Charge | Q _{gs} | $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$ | | 18 | | nC |
| Gate-Drain Charge | Q _{gd} | | | 10 | | |
| Gate Resistance | R _g | | 0.6 | 1.3 | 2.0 | Ω |
| Turn-On Delay Time | t _{d(on)} | | | 24 | 35 | |
| Rise Time | t _r | V_{DD} = 15 V, R_L = 15 Ω | | 16 | 25 | |
| Turn-Off Delay Time t _{d(off} | | $I_D \cong 1 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_g = 6 \Omega$ | | 90 | 140 | ns |
| Fall Time | t _f | | | 32 | 50 | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 2.9 A, dl/dt = 100 A/μs | | 45 | 70 | |

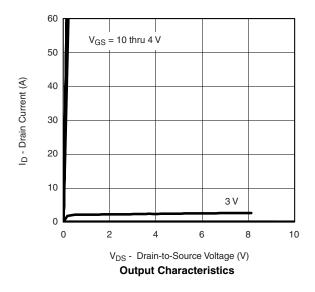
Notes:

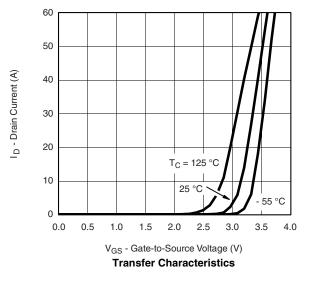
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



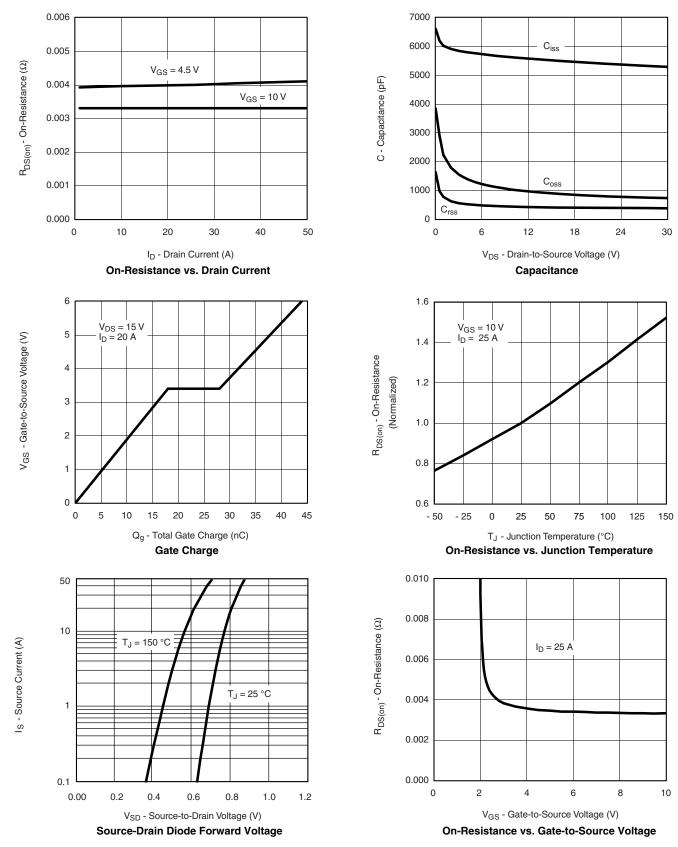


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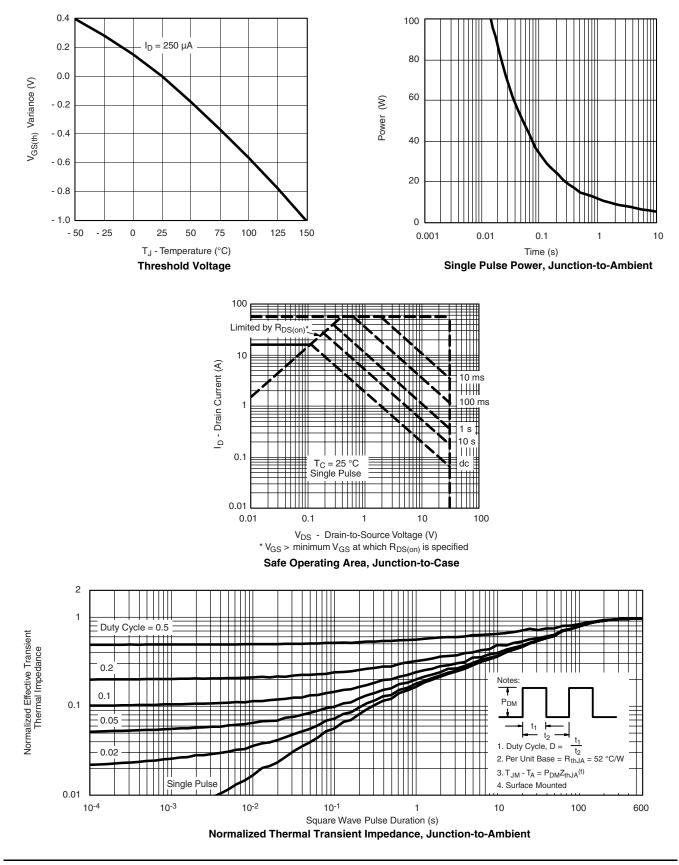


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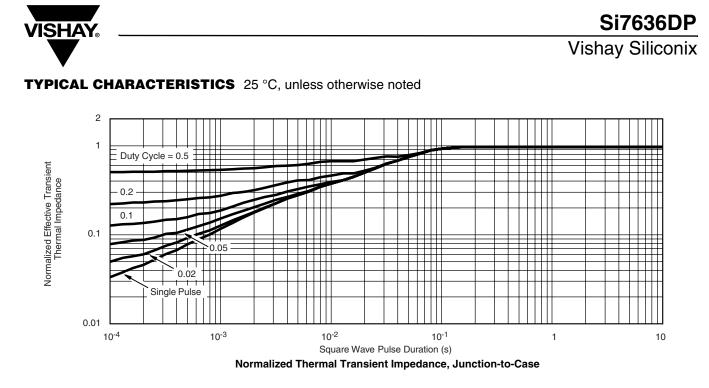
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VISHA



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72768.



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